NSN 5961-00-189-4676

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-189-4676
Inclosure Material:
Metal
Overall Length:
1.646 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.562 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 nonrepetitive peak reverse voltage, peak total value
Current Rating Per Characteristic:
16.00 amperes forward current, average absolute
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Special Features:
Internal junction configuration arrangement pnpn
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0